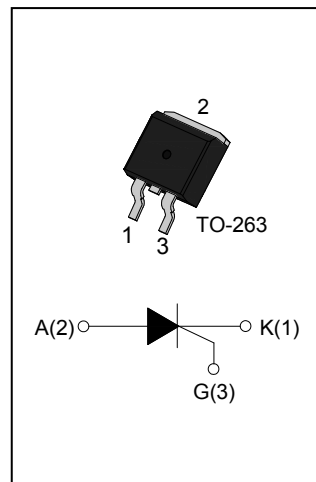




DESCRIPTION:

With high ability to withstand the shock loading of large current, JCTx20 SCRs provide high dv/dt rate with strong resistance to electromagnetic interference. They are especially recommended for use on solid state relay, motorcycle, power charger, T-tools etc. Package TO-263 is RoHS compliant. (2011/65/EU)



MAIN FEATURES

| Symbol | JCT620 | JCT820 |
|-------------------|-------------|--------|
| V_{DRM}/V_{RRM} | 600V | 800V |
| $I_{T(RMS)}$ | 20A | |
| I_{GT} | $\leq 25mA$ | |

ABSOLUTE MAXIMUM RATINGS

| Parameter | Symbol | Value | Unit |
|--|--------------|---------|-------------|
| Storage junction temperature range | T_{stg} | -40-150 | $^{\circ}C$ |
| Operating junction temperature range | T_j | -40-150 | $^{\circ}C$ |
| Repetitive peak off-state voltage($T_j=25^{\circ}C$) | V_{DRM} | 600/800 | V |
| Repetitive peak reverse voltage($T_j=25^{\circ}C$) | V_{RRM} | 600/800 | V |
| RMS on-state current TO-263 ($T_C=80^{\circ}C$) | $I_{T(RMS)}$ | 20 | A |
| Non repetitive surge peak on-state current ($t_p=10ms$) | I_{TSM} | 250 | A |
| I^2t value for fusing ($t_p=10ms$) | I^2t | 312.5 | A^2s |
| Critical rate of rise of on-state current ($I_G=2 \times I_{GT}$) | di/dt | 50 | $A/\mu s$ |
| Peak gate current | I_{GM} | 4 | A |
| Average gate power dissipation | $P_{G(AV)}$ | 1 | W |
| Peak gate power | P_{GM} | 5 | W |

ELECTRICAL CHARACTERISTICS ($T_j=25^{\circ}\text{C}$ unless otherwise specified)

| Symbol | Test Condition | Value | | | Unit |
|----------|--|-------|------|------|------------------|
| | | MIN. | TYP. | MAX. | |
| I_{GT} | $V_D=12\text{V } R_L=33\Omega$ | - | - | 25 | mA |
| V_{GT} | | - | - | 1.3 | V |
| V_{GD} | $V_D=V_{DRM} T_j=150^{\circ}\text{C } R_L=3.3\text{K}\Omega$ | 0.2 | - | - | V |
| I_L | $I_G=1.2I_{GT}$ | - | - | 70 | mA |
| I_H | $I_T=500\text{mA}$ | - | - | 60 | mA |
| dV/dt | $V_D=2/3V_{DRM}$ Gate Open $T_j=150^{\circ}\text{C}$ | 200 | - | - | V/ μs |

STATIC CHARACTERISTICS

| Symbol | Parameter | | Value(MAX) | Unit |
|-----------|---|---------------------------|------------|---------------|
| V_{TM} | $I_{TM}=40\text{A } t_p=380\mu\text{s}$ | $T_j=25^{\circ}\text{C}$ | 1.55 | V |
| I_{DRM} | $V_D=V_{DRM} V_R=V_{RRM}$ | $T_j=25^{\circ}\text{C}$ | 5 | μA |
| I_{RRM} | | $T_j=150^{\circ}\text{C}$ | 4 | mA |

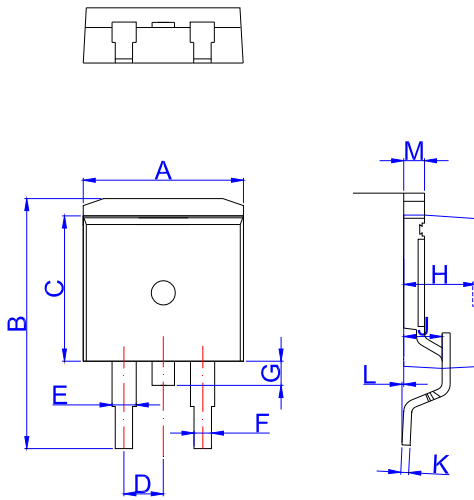
THERMAL RESISTANCES

| Symbol | Parameter | | Value | Unit |
|---------------|----------------------|--------|-------|----------------------|
| $R_{th(j-c)}$ | junction to case(AC) | TO-263 | 2.5 | $^{\circ}\text{C/W}$ |
| $R_{th(j-a)}$ | junction to ambient | | 45 | |

ORDERING INFORMATION

| | | | | |
|---------------------------------|--|-----------------------|---------------------------------------|---|
| JieJie Microelectronics Co.,Ltd | J SCRs 6: $V_{DRM} / V_{RRM} \geq 600\text{V}$ 8: $V_{DRM} / V_{RRM} \geq 800\text{V}$ | CT 6 | 20 $I_{T(RMS)}: 20\text{A}$ | E E: TO-263 ETR: TO-263(Tape&Reel) |
|---------------------------------|--|-----------------------|---------------------------------------|---|

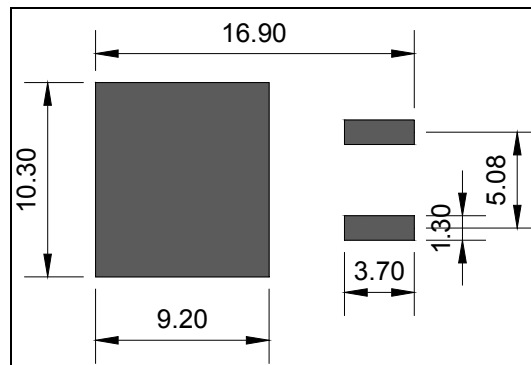
PACKAGE MECHANICAL DATA



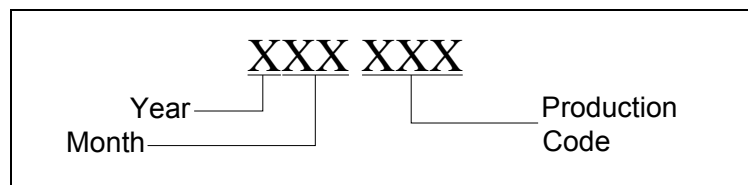
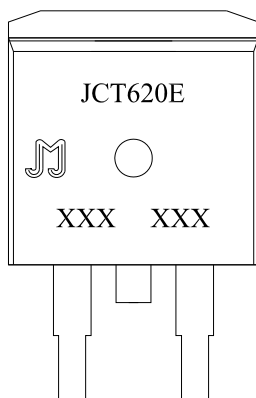
TO-263

| Ref. | Dimensions | | | | | |
|------|-------------|------|-------|--------|-------|-------|
| | Millimeters | | | Inches | | |
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | 9.90 | | 10.20 | 0.390 | | 0.402 |
| B | 14.70 | | 15.80 | 0.579 | | 0.622 |
| C | 9.4 | | 9.6 | 0.37 | | 0.378 |
| D | | 2.54 | | | 0.100 | |
| E | 1.20 | | 1.40 | 0.047 | | 0.055 |
| F | 0.75 | | 0.85 | 0.029 | | 0.033 |
| G | | | 1.75 | | | 0.069 |
| H | 4.40 | | 4.70 | 0.173 | | 0.185 |
| J | 2.30 | | 2.70 | 0.091 | | 0.106 |
| K | 0.38 | | 0.55 | 0.015 | | 0.022 |
| L | 0 | 0.10 | 0.25 | 0 | 0.004 | 0.010 |
| M | 1.25 | | 1.35 | 0.049 | | 0.053 |

FOOTPRINT-TO-263 (dimensions in mm)



MARKING



PACKAGE INFORMATION

| PACKAGE | OUTLINE | TUBE (PCS) | INNER BOX (PCS) | PER CARTON |
|---------|---------|------------|------------------|-------------|
| TO-263 | TUBE | 50 | 1,000 | 6,000 |
| TO-263 | TUBE | 50 | 1,000 | 8,000 |
| PACKAGE | OUTLINE | REEL (PCS) | PER CARTON (PCS) | TAPE & REEL |
| TO-263 | TAPING | 800 | 4,000 | 13 inch |

FIG.1: Maximum power dissipation versus RMS on-state current

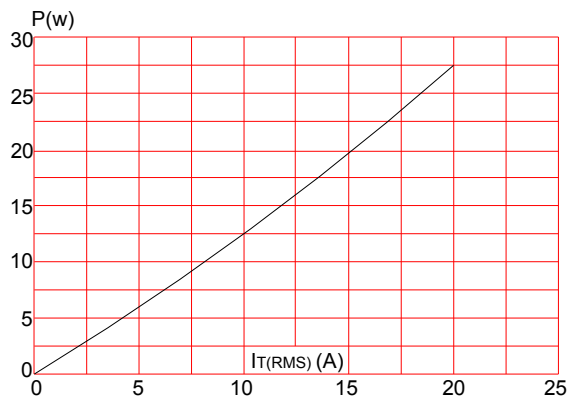


FIG.3: Surge peak on-state current versus number of cycles

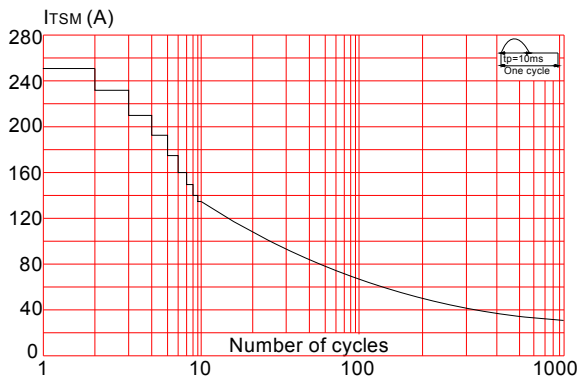


FIG.2: RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness:35μm)(full cycle)

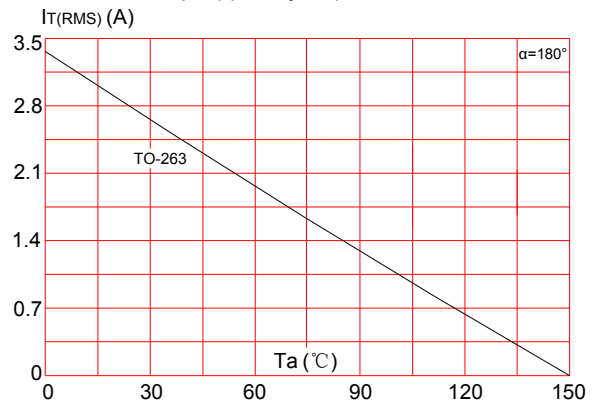


FIG.4: On-state characteristics (maximum values)

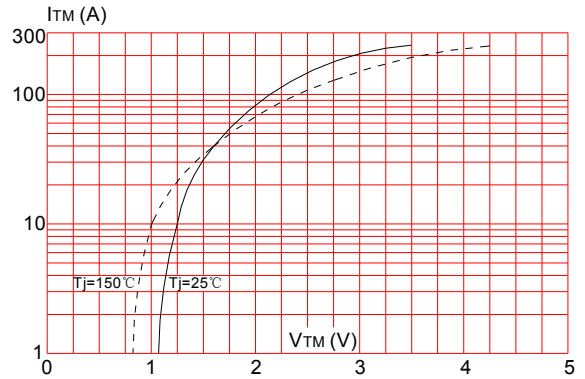


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ms}$, and corresponding value of I^2t

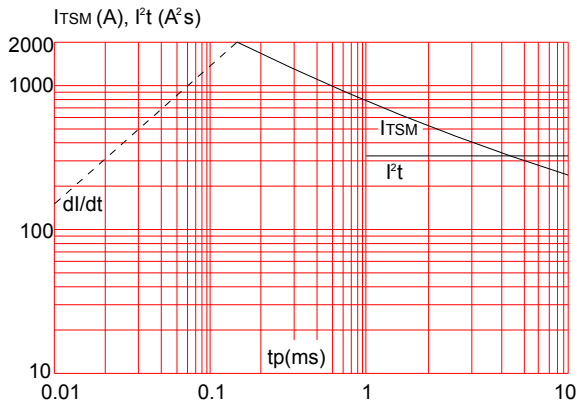
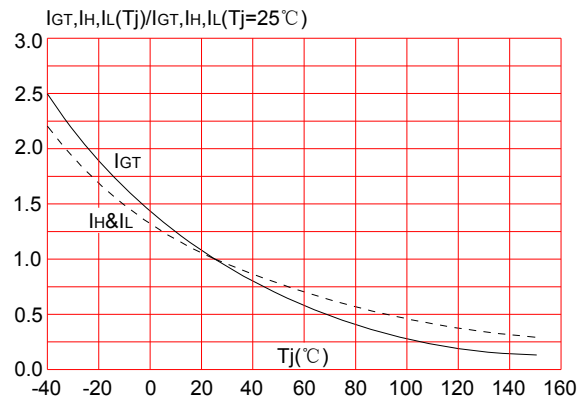
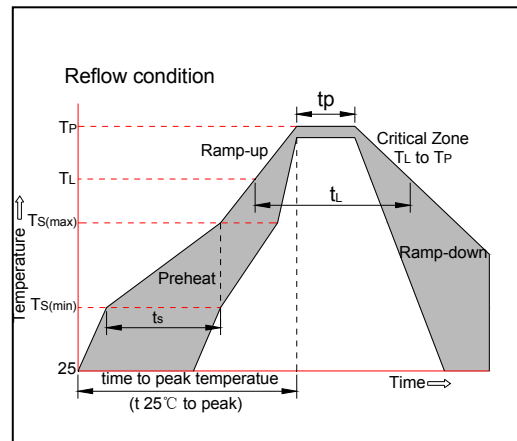


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature




SOLDERING PARAMETERS

| | | |
|---|---|---|
| Reflow Condition | | Pb-Free assembly (see figure at right) |
| Pre Heat | -Temperature Min ($T_{s(\text{min})}$) | +150°C |
| | -Temperature Max ($T_{s(\text{max})}$) | +200°C |
| | -Time (Min to Max) (t_s) | 60-180 secs. |
| Average ramp up rate (Liquidus Temp (T_L) to peak) | | 3°C/sec. Max |
| $T_{s(\text{max})}$ to T_L - Ramp-up Rate | | 3°C/sec. Max |
| Reflow | -Temperature(T_L) (Liquidus) | +217°C |
| | -Temperature(t_L) | 60-150 secs. |
| Peak Temp (T_P) | | +260(+0/-5)°C |
| Time within 5°C of actual Peak Temp (t_p) | | 20-40secs. |
| Ramp-down Rate | | 6°C/sec. Max |
| Time 25°C to Peak Temp (T_P) | | 8 min. Max |
| Do not exceed | | +260°C |



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